گروه فنی مهندسی جوش و برش مقدم

اعتماد از شما کیفیت و تخصص از ما

 \bigcirc

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مشهد خیام شمالی 63 خیابان پردیس 3

برای کسب اطلاعات بیشتر بر روی لینک ها کلیک کنید

- 7 سال سابقه آموزش تعميرات تخصصي دستگاه هاي
 - جوش اینورتری تک فاز و 3 فاز
- 7 سال سابقه فروش قطعات الکترونیکی دستگاه جوش
 تک فاز و 3 فاز
 - آموزش تخصصی تحلیل دستگاه های جوش اینورتری مختص ابراز فروشان
 - آموزش تخصصی ابراز آلات شارژی

TIP41A / TIP41B / TIP41C NPN Epitaxial Silicon Transistor

Features

- · Medium Power Linear Switching Applications
- Complement to TIP42 Series

Ordering Information

Part Number	Top Mark	Package	Packing Method
TIP41A	TIP41A	TO-220 3L (Single Gauge)	Bulk
TIP41B	TIP41B	TO-220 3L (Single Gauge)	Bulk
TIP41C	TIP41C	TO-220 3L (Single Gauge)	Bulk
TIP41CTU	TIP41C	TO-220 3L (Single Gauge)	Rail

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be opera- ble above the recommended operating conditions and stressing the parts to these levels is not recommended. In addi- tion, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter		Value	Unit	
		TIP41A	60		
V _{CBO}	Collector-Base Voltage	TIP41B	80	V	
		TIP41C	100		
		TIP41A	60		
V _{CEO}	Collector-Emitter Voltage	TIP41B	80	V	
		TIP41C	100		
V _{EBO}	Emitter-Base Voltage		5	V	
Ι _C	Collector Current (DC)		6	A	
I _{CP}	Collector Current (Pulse)		10	A	
Ι _Β	Base Current		2	A	
TJ	Junction Temperature		150	°C	
T _{STG}	Storage Temperature Range		-65 to 150	°C	

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Publication Order Number: TIP41C/D

Thermal Characteristics

Values are at $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Value	Unit
P _C	Collector Dissipation ($T_C = 25^{\circ}C$)	65	W
	Collector Dissipation ($T_A = 25^{\circ}C$)	2	vv

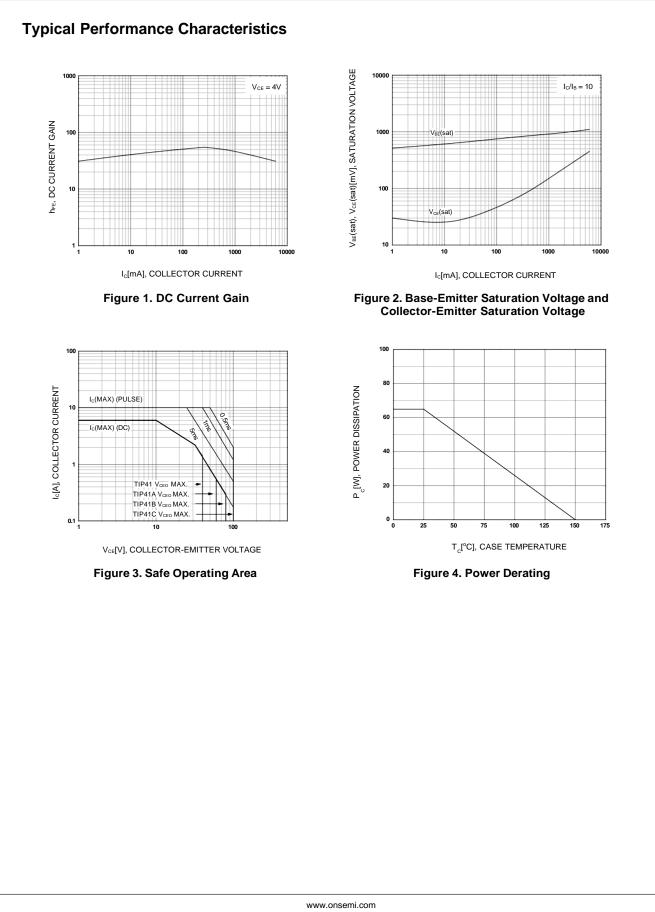
Electrical Characteristics

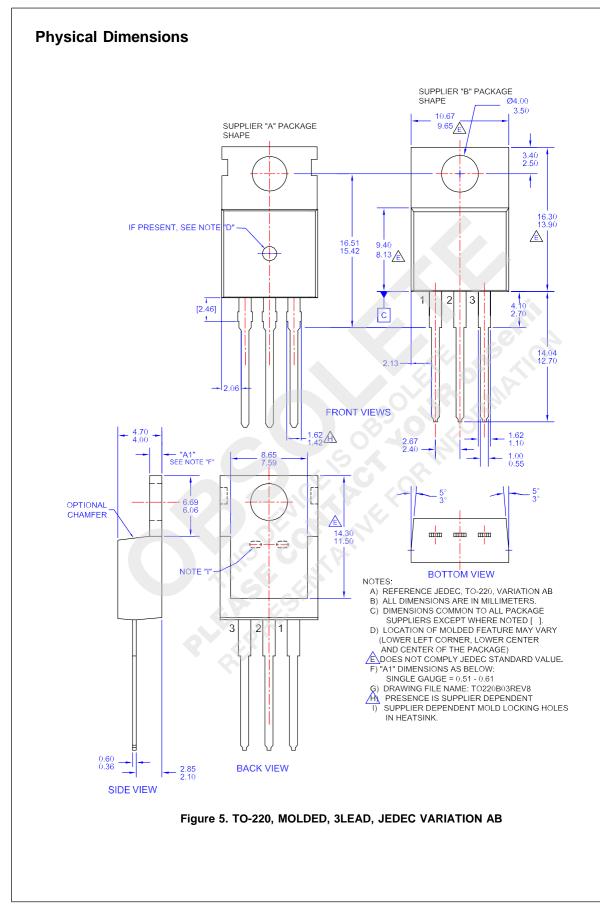
Values are at $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter		Conditions	Min.	Max.	Unit
V _{CEO} (sus)	Collector-Emitter Sustaining Voltage ⁽¹⁾	TIP41A	I _C = 30 mA, I _B = 0	60		v
		TIP41B		80		
		TIP41C		100		
I _{CEO}	Collector Cut-Off Current	TIP41A	$V_{CE} = 30 \text{ V}, I_B = 0$		0.7	mA
		TIP41B/ TIP41C	$V_{CE} = 60 \text{ V}, I_B = 0$		0.7	
I _{CES}	Collector Cut-Off Current	TIP41A	$V_{CE} = 60 \text{ V}, \text{ V}_{EB} = 0$		400	μΑ
		TIP41B	V _{CE} = 80 V, V _{EB} = 0		400	
		TIP41C	V _{CE} = 100 V, V _{EB} = 0		400	
I _{EBO}	Emitter Cut-Off Current		$V_{EB} = 5 V, I_{C} = 0$		1	mA
h _{FE}	DC Current Gain ⁽¹⁾		$V_{CE} = 4 V, I_{C} = 0.3 A$	30		
			$V_{CE} = 4 V, I_{C} = 3 A$	15	75	
V _{CE} (sat)	Collector-Emitter Saturation Voltage ⁽¹⁾		$I_{\rm C} = 6 \text{ A}, I_{\rm B} = 600 \text{ mA}$		1.5	V
V _{BE} (on)	Base-Emitter On Voltage ⁽¹⁾		$V_{CE} = 4 V, I_{C} = 6 A$		2.0	V
fT	Current Gain Bandwidth Product		$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 500 \text{ mA},$ f = 1 MHz	3.0		MHz

Note:

1. Pulse test: $pw \leq 300~\mu s,~duty~cycle \leq 2\%.$







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